



25RIA.. SERIES

PHASE CONTROL THYRISTORS

Stud Version

Features

- Hermetic ceramic -metal seal
- high dv/dt
- tested according to IEC standards
- High surge capability
- Compression Bonded Encapsulation for heavy duty operations such as severe thermal cycling

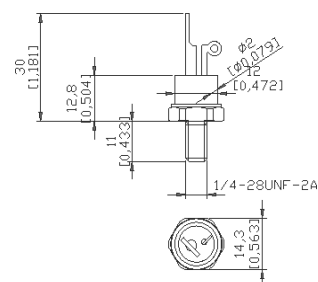
25A

Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

Major Ratings and Characteristics

Parameters	25RIA..	Units
$I_{T(AV)}$	25	A
	@ T_c	85 °C
$I_{T(RMS)}$	40	A
I_{TSM}	@ 50Hz	350 A
	@ 60Hz	365 A
$I^2 t$	@ 50Hz	760 A ² s
	@ 60Hz	710 A ² s
V_{DRM} / V_{RRM}	400 to 1600	V
T_q	typical	150 μ s
T_j	range	- 40 to 125 °C



case style
TO-48



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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} / V_{DRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non- repetitive peak rev. voltage V	I_{RRM} / I_{DRM} max. @ $T_J = T_J$ max. mA
25RIA..	04	400	500	30
	08	800	900	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

On-state Conduction

Parameter		25RIA..	Units	Conditions			
I _{T(AV)}	Maximum average on-state current	25	A	180° conduction, half sine wave			
	@ Case temperature	85	°C				
I _(RMS)	Maximum RMS on-state current	160	A	180° conduction, half sine wave @ T _c = 80°C			
I _{TSM} ,	Maximum peak, one-cycle non-repetitive surge current	350	A	t = 10ms	No voltage reappplied	Sinusoidal half wave, Initial T = T max.	
		365		t = 8.3ms			
		280		t = 10ms	100% V _{RRM}		
		290		t = 8.3ms	reappplied		
I ² t	Maximum I ² t for fusing	760	A ² s	t = 10ms	No voltage		
		710		t = 8.3ms	reappplied		
		490		t = 10ms	100% V _{RRM}		
		470		t = 8.3ms	reappplied		
I ² √ t	Maximum I ² √ t for fusing	7600	A ² √ s	t = 0.1 to 10ms, no voltage reappplied			
V _{TM}	Maximum on-state or forward	1.8	V	pk =750A, T _J = 25°C, t _p = 10ms sine pulse			
I _H	Maximum holding current	200	mA	T _J = 25°C, anode supply 12V resistive load			
I _L	Typical latching current	350					

Switching

Parameter	25RIA..	Units	Conditions
di/dt ax. non-repetitive rate of rise of turned-on current	200	A/ μs	Gate drive 20V, 20 Ω , t _r ≤ 1 μs $T_J = T_J$ max, anode voltage ≤ 80% V_{DRM}
t _d ical delay time	1.0	μs	Gate current 1A, dig/dt = 1A/ μs $V_d = 0.67\% V_{DRM}$, $T_J = 25^\circ\text{C}$
T _q pical turn-off time	150	μs	I _{TM} = 300A, $T_J = T_J$ max, di/dt = 20A/ μs , V _R = 50V dv/dt = 20V/ μs , Gate 0V 100 Ω , t _p = 500 μs



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Blocking

Parameter	25RIA..	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	400	V/ μ s	$T_J = T_J \text{ max linear to } 80\% \text{ rated } V_{DRM}$
I_{DRM} Max. peak reverse and off-state leakage current	15	mA	$T_J = T_J \text{ max, rated } V_{DRM}/V_{RRM} \text{ applied}$

Triggering

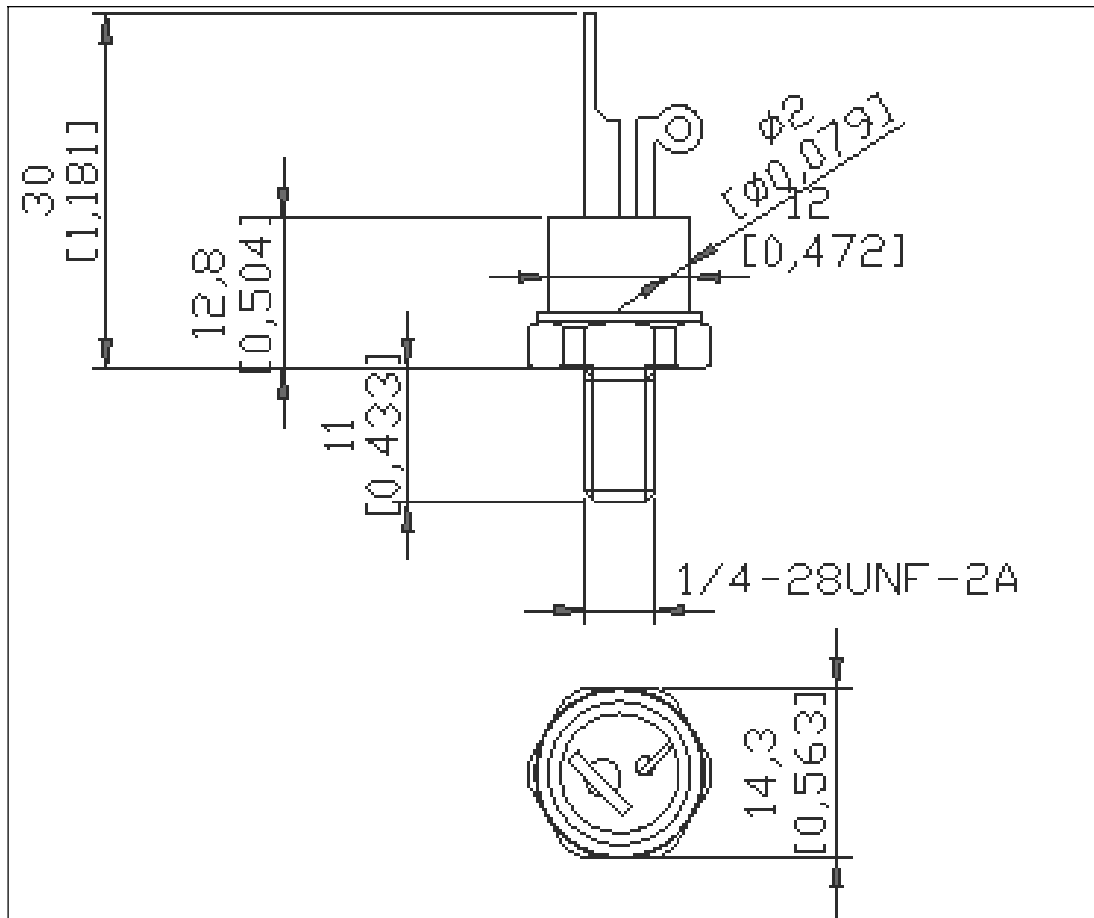
Parameter	25RIA..	Units	Conditions
P_{GM} Maximum peak gate power	13	W	$T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
$P_{G(AV)}$ Maximum average gate power	3.0		$T_J = T_J \text{ max, } f = 50\text{Hz, } d\% = 50$
I_{GM} Max. peak positive gate current	3.0	A	$T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
$-V_{GM}$ Maximum peak negative gate voltage	8		
I_{GT} DC gate current required to trigger	TYP.	MAX.	$T_J = -40^\circ\text{C}$ $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$ Max. required gate trigger/ current/ voltage are the lowest value which will trigger all units 12V anode-to-cathode applied
	100	-	
	50	100	
	10	-	
V_{GT} DC gate voltage required to trigger	2.9	-	$T_J = -40^\circ\text{C}$ $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$
	1.8	3.0	
	0.5	-	
I_{GD} DC gate current not to trigger	8	mA	$T_J = T_J \text{ max}$ Max. gate current/ voltage not to trigger is the max. value which will not trigger any unit with rated V anode-to-cathode applied
V_{GD} DC gate voltage not to trigger	0.25	V	

Thermal and Mechanical Specification

Parameter	25RIA..	Units	Conditions
T_J Max. operating temperature range	-40 to 125	$^\circ\text{C}$	
T_{stg} Max. storage temperature range	-40 to 150		
R_{thJC} Max. thermal resistance, junction to case	0.80	K/W	DC operation
R_{thCS} Max. thermal resistance, case to heatsink	0.40		Mounting surface, smooth, flat and greased
T Mounting torque, $\pm 10\%$	3	Nm	Non lubricated threads
	25	(lbf-in)	Lubricated threads
wt Approximate weight	15	g	



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